



Product Overview

BC858BW: PNP Bipolar Transistor

For complete documentation, see the data sheet

Product Description

The NPN Bipolar Transistor is designed for general purpose amplifier applications. It is housed in the SOT-323/SC-70 package, which is designed for low power surface mount applications.

Features

- Device Marking:
BC856AWT1 = 3A
BC856BWT1 = 3B
BC857AWT1 = 3E
BC857BWT1 = 3F
BC858AWT1 = 3J
BC858BWT1 = 3K
BC858CWT1 = 3L
- Pb-Free Packages are Available
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

Part Electrical Specifications

| Product | Compliance | Status | Polarity | I _C Continuous (A) | V _{(BR)CEO} Min (V) | h _{FE} Min | h _{FE} Max | f _T Min (MHz) | P _{TM} Max (W) | Package Type |
|------------|---|--------|----------|-------------------------------|------------------------------|---------------------|---------------------|--------------------------|-------------------------|---------------------|
| BC858BWT1G | AEC Qualified Pb-free Halide free | NEW | PNP | 0.1 | 30 | 220 | 475 | 100 | 0.15 | SC-70-3 / SOT-323-3 |

For more information please contact your local sales support at www.onsemi.com

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